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# Parameter Stability Region Analysis of Islanded Microgrid Based on Bifurcation Theory

Zhikang Shuai, Senior Member, IEEE, Yelun Peng, Xuan Liu, Member, IEEE, Zuyi Li, Senior Member, IEEE, Josep M. Guerrero, Fellow, IEEE and John Shen, Fellow, IEEE

Abstract-- This paper studies the parameter stability region of droop-controlled AC microgrid (MG) with static ZIP (constant impedance, constant current, constant power) load and dynamic induction motor (IM) load using bifurcation theory. First, the dynamic model of the MG with ZIP and IM loads is developed. Next, bifurcation analysis is used to predict the bifurcation boundaries where microgrid becomes unstable. Saddle node and hopf bifurcation are detected in the studied system when parameters change. The stability region in parameters space is bounded by bifurcation boundaries. To improve the computing efficiency for predicting the stable region of parameters, the reduced-order models of MGs are developed based on singular perturbation method. Finally, numerical simulations and experiment are used to verify the analysis result and the effectiveness of the proposed strategy.

*Index Terms--* Islanded microgrid, parameter stability region, bifurcation theory, reduced-order model, singular perturbation method.

#### I. INTRODUCTION

The Microgrids (MGs) that serve as individual controllable systems can integrate distributed generators (DGs) and supply power to local loads with or without external power systems [1]. The low-inertia and limited capabilities of inverter make MG vulnerable to instability when subject to disturbances [2-4]. In practical case, multiple types of load are considered in MG system, such as resistance load, constant power load and induction motor (IM) load. To achieve stable operation, the parameter stability region of MG with multitype loads need to be predicted [5].

Small-signal analysis has been widely used to investigate the stability of the linearized system under a set of specific parameter configuration [6-9]. However, when system parameters change, the equilibrium is accordingly changed and deviates from the predefined linearization point [10-14]. To plot the stability constraint of parameters, the linearization and eigenvalue calculation are performed iteratively, which is labor-consuming and inefficient.

The bifurcation analysis has been proposed to predict the parameter stability boundary of nonlinear system. Bifurcation occurs when a small continuously change of parameter values causes a sudden change in system behavior [14]. Compared with the small-signal analysis that analyzes the perturbation of a fixed equilibrium, the bifurcation analysis can perform parametric stability analysis that traces equilibrium solutions as the parameters change [15-16]. In [17-19], the bifurcation theory was used to predict the parameter stability region of MG. However, only RL load [17-18] and rectifier served as a constant-power load [19] are considered. ZIP (constant impedance, constant current, constant power) load is widely used to describe a practical static load, which is rarely considered in current MG models. In [20], the progressive increment of IM load was given by placing identical IMs in parallel. However, the MG model is changed with the increase of connected IMs, which prevents the continuous tracing of the equilibrium manifold. So far, the bifurcation analysis for MG with ZIP and IM load have not been discussed.

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Another problem of the stability-region analysis is the high dimension of MG model, which results in a huge computation burden. Singular perturbation method has been proposed to reduce the model order by eliminating the fast dynamics [21-24]. However, the coupling of dynamics makes the reduced model inaccurate for predicting different boundary. In [25-27], the reduced model for predicting the stability region of active-power droop gain are proposed. However, these model present errors for predicting the stability boundary of other parameters, such as reactive power droop gain.

This paper extends the application of bifurcation theory to analyze the parameter stability region of the MG with static ZIP load and dynamic IM load. The main contributions of this paper can be summarized as follows:

(1) The equivalent model of static ZIP loads and dynamic IM loads have been developed, respectively, for the continuous tracing of the load increasing in MG model.

(2) The parameter stability region analysis based on bifurcation theory is performed for the MG with ZIP load and IM load. Bifurcation phenomena of MG with parameters change are observed. The stability boundaries of MG in terms of the key control parameters and load are investigated in detail.

(3) The reduced models for predicting different bifurcation boundaries are developed. The reduced model for predicting a specific bifurcation phenomenon preserves the states variables that has major influence on the corresponding bifurcation.

The rest of this paper is organized in the following way:

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Section II describes the dynamic model of MGs with ZIP and IM loads. In Section III, bifurcation method is proposed to predict the parameter stability region of MG. In Section IV, the reduced models for stability region analysis are proposed. In Section V, simulation and experiment results are given to verify the bifurcation analysis results. Section VI concludes this paper.

#### II. MODELING OF THE MICROGRID WITH ZIP AND IM LOAD

This section provides the microgrid model with ZIP and IM load. The MG model consists of the droop-controlled DG, dynamic IM load, static ZIP load, and network. The equivalent model of IM and ZIP load will be presented in detail.

#### A. Model of the Droop-Controlled DG

The block diagram of a droop-controlled DG is depicted in Fig. 1 [6]. The control system is composed of droop controller for power sharing and inner control loops for voltage and current control. The droop controller mimics the active-power and reactive-power droop characteristics of synchronous generator. The droop controller compares the filtered active power P and reactive power Q to the command values, and outputs the frequency command  $\omega$  and voltage reference  $u_0^{ref}$ . The inner-control loop is designed under the dq synchronous reference frame for voltage tracking with zero steady-state error. The PI controller for voltage control compares the  $u_o^{ref}$  and 0 to the capacitor voltage  $u_{od}$  and  $u_{oq}$ , respectively, and outputs the current reference  $i_{ld}^{ref}$  and  $i_{lq}^{ref}$ . The obtained current references are sent to the current controller where the measured current  $i_{ld}$ and  $i_{lq}$  are compared to  $i_{ld}^{ref}$  and  $i_{lq}^{ref}$ , respectively. Command voltage  $u_{id}$ ,  $u_{iq}$  are given via the current controller and transformed into abc reference frame for PWM generation.

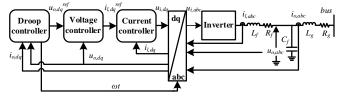


Fig. 1. Block diagram of droop-controlled inverter.

The mathematical model of droop-controlled inverter in [6] is adopted in this paper. The droop-controlled DG incorporates 12 states to describe its dynamic behavior, whose state variables are written as follows:

 $x_{DG} = [\theta, P, Q, u_{od}, u_{oq}, i_{ld}, i_{lq}, i_{od}, i_{oq}, \varphi_d, \varphi_q, \gamma_d, \gamma_q]$ where  $\varphi_d, \varphi_q, \gamma_d, \gamma_q$  are the dynamic states of PI controllers.

## B. Model of the Induction Motor Load

Squirrel cage IM is selected in this work as a kind of typical IM load. The electromagnetic transients of rotor and stator sides are both considered. The flux equations of IM can be written as:

$$\psi_{sD} = L_s i_{sD} + L_m i_{rD}, \psi_{sQ} = L_s i_{sQ} + L_m i_{rQ}, \qquad (1)$$

$$\Psi_{rQ} = L_r i_{rD} + L_m i_{sD}, \Psi_{rQ} = L_r i_{rQ} + L_m i_{sQ}, \qquad (2)$$

where  $L_m$  is the linkage inductance,  $L_s$  and  $L_r$  are the stator inductance and rotor inductance, respectively. The voltage equations of IM are written as:

$$u_{sD} = R_s i_{sD} + \dot{\psi}_{sD} - \omega_{com} \psi_{sQ}, \qquad (3)$$

$$u_{sQ} = R_s i_{sQ} + \dot{\psi}_{sQ} + \omega_{com} \psi_{sD}, \qquad (4)$$

$$0 = R_r i_{rD} + \dot{\psi}_{rD} - (\omega_{com} - \omega_r) \psi_{rO} , \qquad (5)$$

$$0 = R_r i_{rO} + \dot{\psi}_{rO} + (\omega_{com} - \omega_r) \psi_{rD}, \qquad (6)$$

where  $R_s$  and  $R_r$  are the stator resistance and rotor resistance, respectively. Substituting (1-2) into (3-6) and the cooperating rotor motion equation, the dynamic model of the IM can be written as:

$$\dot{\omega}_{\rm r} = \frac{n_p^2 L_m}{J L_r} (i_{sQ} \psi_{rD} - i_{sD} \psi_{rQ}) - \frac{n_p}{J} T_l \,, \tag{7}$$

$$\dot{\psi}_{rD} = -\frac{1}{T_r} \psi_{rD} + (\omega_{com} - \omega) \psi_{rQ} + \frac{L_m}{T_r} i_{sD}, \qquad (8)$$

$$\dot{\psi}_{rQ} = -\frac{1}{T_r} \psi_{rQ} - (\omega_{com} - \omega) \psi_{rD} + \frac{L_m}{T_r} i_{sQ}, \qquad (9)$$

$$\dot{i}_{sD} = \frac{L_m}{\sigma L_s L_r T_r} \psi_{rD} + \frac{L_m}{\sigma L_s L_r} \omega_{com} \psi_{rQ} - \frac{R_s L_r^2 + R_r L_m^2}{\sigma L_s L_r^2} \dot{i}_{sD} + \omega_{com} \dot{i}_{sQ} + \frac{u_{bD}}{\sigma L_s}$$
(10)

$$\dot{i}_{sQ} = \frac{L_m}{\sigma L_s L_r T_r} \psi_{rQ} - \frac{L_m}{\sigma L_s L_r} \omega_{com} \psi_{rD} - \frac{R_s L_r^2 + R_r L_m^2}{\sigma L_s L_r^2} i_{sQ} - \omega_{com} i_{sD} + \frac{u_{bQ}}{\sigma L_s}$$
(11)

where J is the rotor inertia coefficient.  $\sigma = 1 - \frac{L_m^2}{L_s L_r}$  denotes the

leakage factor and  $T_r = L_r/R_r$  represents the rotor electromagnetic time constant. The load torque can be described by the following nominal as:

$$T_1 = T_0 + T_1 \omega + T_2 \omega^2$$
. (12)

The incremental IM load at a given bus can be obtained by placing identical IMs in parallel. However, to track the increment of IM loads, the number of integrated IMs increases at the given bus, which will change the structure and increase the size of MG model. On the other hand, the paralleled IMs can be presented as a single-unit equivalent IM based on the dynamic equivalent method. By doing so, the continuous load increment can be presented as the parameters change of the equivalent IM.

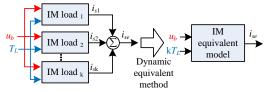


Fig.2. Bock diagram of paralleled IM loads and their equivalent model.

Fig.2 presents the signal flow of an IM model, the input signals of IM loads are bus voltage  $u_b$  and load torque  $T_L$ , stator current  $i_s$  is the output signal. To provide the same dynamic behavior with the original paralleled IMs, the dynamic equivalent model of IMs must meet the following requirements:

1) The voltage and current on the connected bus do not change.

2) The active and reactive power assumption of equivalent IMs must be equal to the sum of all the power assumption at the connected bus of paralleled IMs.

3) The electromagnetic time constant of the equivalent IM equal to that of the paralleled IMs.

According to the first condition, the stator current and bus voltage of the equivalent IM should satisfy

$$\dot{i}_{sDe} = \sum i_{sD} = K i_{sD}, \\ \dot{i}_{sQe} = \sum i_{sQ} = K i_{sQ}.$$
(13)

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As the stator voltage keeps unchanged, the stator and rotor flux of the equivalent IM are obtained as:

$$\Psi_{rDe} = \Psi_{rD}, \Psi_{rQe} = \Psi_{rQ}, \Psi_{sDe} = \Psi_{sD}, \Psi_{sQe} = \Psi_{sQ}.$$
 (14)

According to the second condition, the load torque and rotor angular velocity are:

$$\omega_{\rm re} = \omega_{\rm r}, T_{Le} = \sum T_L = K T_L.$$
(15)

From the third condition, the electrical parameters of the equivalent IM should meet the relationship below:

$$T_{se} = T_s = L_s / R_s, T_{re} = T_r = L_r / R_r.$$
 (16)

Substituting (13-16) into the flux and voltage equations (7-11), the parameters of the equivalent motor load rated at  $P_{IM}=KP_nW$  can be described by an IM load factor K:

$$L_{me} = L_m / K, L_{se} = L_s / K, R_{se} = R_s / K, L_{re} = L_r / K, R_{re} = R_r / K, J_e = KJ, T_{Le} = KT_L$$
(17)

Therefore, based on a typical motor load rated at  $P_n$ W, the parameters of the equivalent motor load rated at  $P_{IM}=KP_n$ W can be described by (17). Thus, the continuous increment of IM load is described by increasing load coefficient *K*.

## C. Model of ZIP Load

ZIP loads are often used in static analyses and are packaged in many commercial software tools (such as PSCAD and Matlab/SimPowerSystems.). The load consumption of ZIP load can be represented by the polynomials as:

$$P_{ZIP} = P_0 \left( a_1 \frac{U_b^2}{U_0^2} + a_2 \frac{U_b}{U_0} + a_3 \right), Q_{ZIP} = Q_0 \left( b_1 \frac{U_b^2}{U_0^2} + b_2 \frac{U_b}{U_0} + b_3 \right), (18)$$

where  $P_0$  and  $Q_0$  are the nominal active-power and reactivepower, respectively under the nominal voltage  $U_0$ .  $a_1$  and  $b_1$ ,  $a_2$ and  $b_2$ , and  $a_3$  and  $b_3$  are the percentages of the constantimpedance load, constant-current load, and constant-power load, respectively, and  $U_b$  denotes the magnitude of bus voltage.

Instead of active and reactive power flows, the line currents are used as the signal flows in the network of microgrid model for describing the line dynamics. Thus, the equation (18) cannot be integrated in MG model directly. Therefore, the parallel combination of conductance  $G_{ZIP}$  and susceptance  $B_{ZIP}$  are used to present ZIP load model depicted in Fig. 3. The  $G_{ZIP}$  and  $B_{ZIP}$  can be described as:

$$G_{ZIP} = P_0 \left(\frac{a_1}{U_0^2} + \frac{a_2}{U_0 U_b} + \frac{a_3}{U_b^2}\right), B_{ZIP} = -Q_0 \left(\frac{b_1}{U_0^2} + \frac{b_2}{U_0 U_b} + \frac{b_3}{U_b^2}\right). (19)$$

From (18), the values of  $G_{ZIP}$  and  $B_{ZIP}$  depend on the magnitude of bus voltage  $U_b$ . The state equations of the ZIP load current can be written on the common reference frame as:

$$\tau \dot{i}_{Pd} = G_{ZIP} u_{bd} - i_{Pd}, \tau \dot{i}_{Pq} = G_{ZIP} u_{bq} - i_{Pq}.$$
(20)

The state equations of the load current of  $B_{ZIP}$  can be presented on the common reference frame as:

$$\tau \dot{i}_{Qd} = -B_{ZIP} u_{bq} - i_{Qd}, \tau \dot{i}_{Qq} = B_{ZIP} u_{bd} - i_{Qq}.$$
(21)

where  $\tau$  is defined as the time constant of ZIP load.

Fig. 3. Equivalent circuit of a ZIP load.

#### D. Model of Microgrid System

To extract all the dynamics in the proposed system, the dynamics of the connecting line between the bus i and bus j can be described as:

$$\dot{i}_{lineD} = (u_{biD} - u_{bjD} - R_{line}i_{lineD} + \omega_{com}L_{line}i_{lQ}) / L_{line}$$
(22)

$$_{lineQ} = (u_{biQ} - u_{bjQ} - R_{line}i_{lineQ} - \omega_{com}L_{line}i_{lineD}) / L_{line}$$
(23)

To define the bus voltage well, a small virtual capacitor  $C_{vir}$  is added between the bus and ground. The voltage of bus *i* can be written as:

$$\dot{u}_{bDi} = \left(\sum i_{oD} - \sum i_{loadD} + \sum i_{lineD} + \omega_{com}C_{vir}u_{bQi}\right) / C_{vir} (24)$$
$$\dot{u}_{bQi} = \left(\sum i_{oQ} - \sum i_{loadQ} + \sum i_{lineQ} - \omega_{com}C_{vir}u_{bDi}\right) / C_{vir} (25)$$

The dynamic model of MG is organized as differentialalgebraic equations. The islanded MG with *m* DGs, *n* lines, *k* IM loads, *l* ZIP loads, and *i* buses has 13m + 2n + 5k + 4l + 2i-1 state variables to describe its dynamics.

#### III. PARAMETER STABILITY-REGION ANALYSIS BASED ON BIFURCATION THEORY

#### A. System Description

In this section, the numerical bifurcation method is applied to analyze the parameter stability region of a microgrid system. The microgrid system is as shown in Fig. 4, which consists of two droop-controlled DGs, a dynamic IM load, and a static ZIP load. DGs and loads are connected through a tie-line with inductance  $L_{line}$  and resistance  $R_{line}$ .

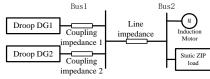


Fig. 4. The microgrid with 2 DGs.

In this MG, the parameters of the two droop-controlled DGs are given in Table I, and the load parameters under the rated operation condition are given in Table II. The inductance and resistance of connection lines are 0.26mH/km and 0.164 $\Omega$ /km respectively. The length of connection line  $L_{line}$ =0.5 km.

TABLE I. DROOP-CONTROLLED DG PARAMETERS

Parameter	Value	Parameter	Value
$P_{n1}, P_{n2}$	40 kW, 20 kW	$L_{f1}, L_{f2}$	1.2 mH, 1.2 mH
$U_{n1}, U_{n2}$	330 V, 330 V	$R_{f1}, R_{f2}$	0.1 Ω, 0.1 Ω
$m_{p1}, m_{p2}$	0.75e <sup>-4</sup> rad/W, 1.5e <sup>-4</sup> rad/W	$C_{fl}, C_{f2}$	0.55 mF, 0.45 mF
$m_{q1}, m_{q2}$	5e <sup>-4</sup> V/Var, 7e <sup>-4</sup> V/Var	$L_{g1}, L_{g2}$	0.6 mH, 0.4 mH
$\omega_c$	31.4 rads/s	$R_{g1}, R_{g2}$	0.3 Ω, 0.2 Ω
$K_{vp1}, K_{vp2}$	1.2, 1	$K_{cp1}, K_{cp2}$	4, 3.2
$K_{vil}, K_{vi2}$	380, 275	$K_{cil}, K_{ci2}$	550, 480

TABLE II. LOAD PARAMETERS

ZIP load parameter	Value	IM load parameter (22.5kW)	Value
$b_1, b_2, b_3$	0.2,0.3,0.5	$L_m$	0.043927 mH
$c_1, c_2, c_3$	0.2.0.3.0.5	$L_r, R_r$	$0.0449 \text{ mH}, 0.228 \Omega$
$P_{0}$	10kW	$L_s, R_s$	$0.0449 \text{ mH}, 0.087 \Omega$
$Q_0$	5kVar	J	1.662 kgm <sup>2</sup>
$U_0$	311V	$T_{0}, T_{1}, T_{2}$	65, 0.5, 0

Bifurcation analysis is a powerful tool to analyze the parameter stability of nonlinear system. The occurrence of local

bifurcation leads the nonlinear system to become unstable. In general, bifurcations are caused by continuous variations of one or more parameters. Using the bifurcation analysis package software MATONT [28], the bifurcation boundaries and solution manifolds of different parameters are plotted. For electrical power system, Hopf bifurcation (HB) and saddle-node bifurcation (SNB) are the major local stability boundaries [18-19]. When SNB occurs, a real eigenvalue is located on the imaginary axis. If the parameters continue to change, the stable equilibrium disappears and the system collapses. When HB occurs, a pair of complex conjugate eigenvalues are on the imaginary axis. After that, the limit circle will emerge, and then the system becomes oscillatory.

#### B. Case1: Bifurcation Analysis on $m_p$ - $m_q$ Plane

The power controller of droop-controlled DG dominates the dynamic behavior of the microgrid. The scheduling of the power droop gains determines the power regulation of microgrids. In this part, the parameters of power controllers including active power gain  $m_p$  and reactive power gain  $m_q$ , are selected to do bifurcation analysis. The influences of cut-off frequency, coupling inductor, and load on the stability region of microgrid are investigated. The starting point of the bifurcation analyses is the equilibrium of MG with the parameters in Table I and Table II. To ensure the power sharing of the two DGs, the ratio between the active power gains of two DGs is maintained at 1:2, and the ratio between the reactive power gains is maintained at 5:7.

Fig. 5 plots the bifurcation diagram of  $m_p$  and  $m_q$ , where the red curves denote the HB boundaries of test system, respectively. Two HB boundaries bound the parameter stability region on  $m_p$ - $m_q$  plane. The proposed MG tends to lose its stability with the increase of  $m_p$  or  $m_q$ . The Lyapunov coefficients on the two HB curves are smaller than 0. Thus, increasing  $m_p$  or  $m_q$  will lead to the subcritical HB1 and HB2, respectively. Besides, increasing reactive-power droop gain  $m_q$  extends the upper limit value of active power gains  $m_p$ . While  $m_p$  has little effect on the upper limit of  $m_q$  and raise the lower limit of  $m_q$ . The feasible region of  $m_q$  narrows when  $m_p$  increases. Thus, when a large  $m_p$  is designed to improve transient response, a large  $m_q$  should be selected to make sure the stability of MG.

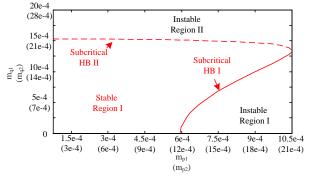


Fig. 5. The parameter stability region on  $m_p$ - $m_q$  plane.

In [21], the stable region of MG with resistance load is plotted on  $m_p$ - $m_q$  using the small-signal analysis. The unstable phenomena are also founded in this test MG model, which are identified as HB phenomena. The phase plane of active power  $P_1$  and reactive power  $Q_1$  before and after subcritical HB1 are plotted in Fig. 6. The red curve denotes the trajectory of operation point before the subcritical HB1 when  $m_{p1} = 4.5e^{-4}$ ,  $m_{ql} = 5e^{-4}$  ( $m_{p2} = 9e^{-4}$ ,  $m_{q2} = 7e^{-4}$ ). The blue curve denotes the trajectory after the subcritical HB when  $m_{pl} = 7.5e^{-4}$ ,  $m_{ql} = 5e^{-4}$  ( $m_{p2} = 15e^{-4}$ ,  $m_{q2} = 7e^{-4}$ ). The subcritical HB1 gives rise to an unstable limit circle around the stable equilibrium. As illustrated, the trajectory after the HB diverges from the start point, and the system becomes oscillatory.

Then, the impacts of the cut-off frequency  $\omega_c$  on the stability region of  $m_p$ - $m_q$  plane are studied. The cut-off frequency of two DGs are both changed. It can be seen from Fig. 7, decreasing the inverter cut-off frequency  $\omega_c$  broadens the stability region. Besides, the extension part of the stability region is the area with a larger reactive power gain  $m_q$ . The extended range of the active power droop gain is only valid when the reactive droop gain increases correspondingly.

Fig. 8 plots the stability region on  $m_p - m_q$  plane when different coupling inductors are selected. As presented in Fig 8, the increase of coupling inductance tends to increase the overall stability region on  $m_p - m_q$  plane, especially in terms of active power gain. That means a weaker coupling between inverters will improve the system stability. It can be noticed that not only a greater inductor but also a substantial virtual impedance can be utilized to broaden the parameter stability region.

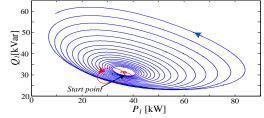


Fig. 6. Phase plane of the microgrid before and after subcritical Hopf bifurcation. Red curve: stable operation; Blue curve: subcritical Hopf bifurcation.

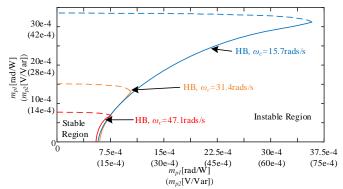


Fig. 7. Hopf bifurcation boundaries for MG with different cut-off frequency.

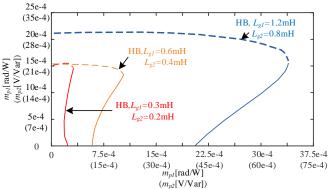


Fig. 8. Hopf bifurcation boundaries for MG with different coupling inductance.

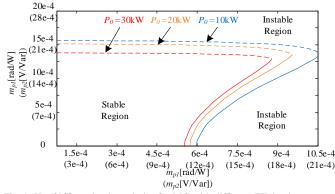


Fig. 9. Hopf bifurcation boundaries for MG with different ZIP load.

Fig. 9 plots the parameter stability region on  $m_p$ - $m_q$  plane when the active power of ZIP load increases from 10kW to 30kW. The stable region of MG shrinks with the increase of ZIP load. The increasing active power load has minor effect on  $m_q$  but narrows the stability region of  $m_p$ .

#### C. Case 2: Bifurcation Analysis on P-V plane

For the MG in islanded mode, the power assumption of a local load can only be provided by the inverter-based DGs. Power unbalance is the major physical mechanism of instability, the maximum power supply of MG should be calculated to make sure its stability. In this part, the bifurcation analyses are performed on P-V plane. The influences of connection line, virtual inductance, reactive power controller on the parameter stability region are investigated.

As presented previously that the parameter stability region on  $m_p$ - $m_q$  plane is highly related to the coupling inductor of inverters. Thus, a large inductor is recommended for improving the stability of microgrid with parallel inverters. However, the installation of bulk inductor is costly. Thus, virtual impedance control has been proposed in the literatures [29] for stability improvement, harmonic mitigation and also for fault ride through. In general, the voltage droop from the virtual inductor that reacts to output current is added on the voltage reference. The modified voltage references can be presented by

$$u_{odi}^{ref} = U_n - m_{qi}Q_i + \omega_0 L_{vi}i_{oqi} - R_{vi}i_{odi} u_{oqi}^{ref} = -\omega_0 L_{vi}i_{odi} - R_{vi}i_{oqi}$$
(26)

This section discusses the parameter stability region of MG when virtual inductor control is implemented. The physical coupling impedance of inverter 1 and 2 are designed as  $0.3+j0.24\pi\Omega$  and  $0.2+j0.16\pi\Omega$ , respectively. The virtual inductor of inverters  $L_{vir}$  is initially set to 4mH.

Fig. 10 plots the equilibrium solution manifold for different types of load on the active-power versus bus voltages (P-V) plane. The nominal reactive-power  $Q_0$  is set to zero. The constant-impedance load, constant-current load, and constant-power load are obtained by setting percentages of ZIP load as a<sub>1</sub>, b<sub>1</sub> = 100%; a<sub>2</sub>, b<sub>2</sub> = 100%, and a<sub>3</sub>, b<sub>3</sub> = 100%, respectively. It can be seen from Fig. 10 that the voltage at bus 2 decreases when the load increases. Then, an SNB point is found in the equilibrium solution manifold of the constant-power load when  $P_0 = 58.17$  kW. An SNB point can also be found in the curve for IM load when the IM load  $P_{IM} = 42.54$  kW. The PCC voltage decreases sharply when the load close to the SNB boundary and their bifurcation point of PCC voltage are around 200V, which indicates the voltage instability phenomenon. The stable

equilibrium will disappear after the SNB, and the nonlinear system loses its stability when the SNB occurs. For the bifurcation curves of constant-impedance and constant-current loads, the bifurcation phenomena do not exist. Therefore, in a ZIP load model, the constant-power component has a significant effect on the stability of MG. In addition, the stability margin of IM load is smaller than that of ZIP load.

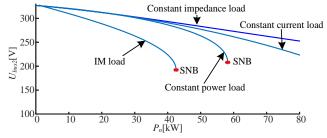


Fig. 10. Equilibrium solution manifold on the  $P_{o^-}U_{bus2}$  plane for load increasing. SNB is saddle-node bifurcation detected in the curve of IM load and constant-power load.

Fig. 11 presents the influence of the connection line with fixed X/R ratio. The increasing the length of connection line tends to shrink the stability region. Besides, the parameter stability region of IM loads is smaller than that of constant power load. As shown in Fig. 12, the increase of virtual coupling inductor moves the SNB boundary to a lower level. Thus, the application of virtual inductance control tends to broaden the parameter stability region on  $m_p$ - $m_q$  plane, but shrinks the stability region on P-V plane. That means, both SNB and Hopf boundaries should be considered for virtual inductance design to keep the safe operation of the microgrid.

Since, the power assumption is related to the voltage regulation. The influence of reactive-power droop control on the SNB is investigated. The Fig. 13 plots stability region of  $m_q$  when virtual inductor is added. In this case, the SNB occurs before the HB for a relatively large load consumption. Moreover, the  $m_q$  limit decrease sharply with load increase. A small value of reactive power gain should be designed for improving the stability when system under heavy load condition. For the  $m_q$  design, there is a trade-off between the accurate reactive-power sharing and maximum power transmission. Fig. 14 plots the SNB when nominal voltage change. It can be seen that decreasing nominal voltage shrink the stable range of load assumption. Since, the nominal voltage may be scheduled on secondary control level, its stable range should be fully evaluated.

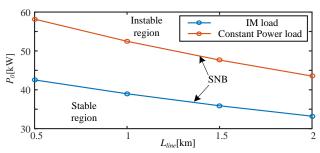


Fig. 11. SNB boundaries for MG with different lengths of connection line.

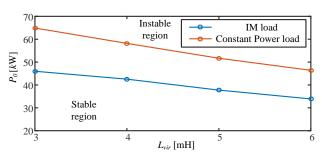


Fig. 12. SNB boundaries for MG when different virtual inductances are selected.

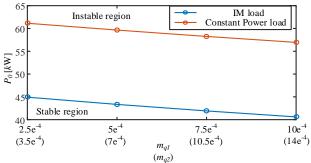


Fig. 13. SNB boundaries of  $P_{\theta}$  for MG when different reactive-power droop gain  $m_q$  are selected.

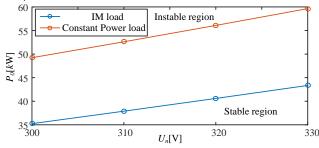


Fig. 14. SNB boundaries of  $P_0$  for MG when different nominal voltage of droop controller  $U_n$  are selected.

From the bifurcation analysis above, several conclusions are obtained as follows:

1) For the MG with ZIP loads and induction motor loads, increasing the active power gain  $m_p$  or reactive power gain  $m_q$  leads to the subcritical HB phenomena. MG becomes oscillating after the subcritical HB whose boundaries constitute the parameter stability region on the  $m_p$ - $m_q$  plane. Decreasing the value of cut-off frequency  $\omega_c$  or increasing the value of coupling inductance broadens the parameter stability region on  $m_p$ - $m_q$  plane. The connected loads have minor effect on the HB boundaries.

2) The increase of an IM load or constant power component of a ZIP load results in the SNB phenomena. The bus voltages of the microgrid collapse after the SNBs. SNB boundaries constitute the parameter stability region for load increasing. Decreasing the value of reactive power gain  $m_q$  or impedance of connection line will broaden the stability region of loads. Increasing the value of nominal voltage  $U_n$  or virtual inductance shrink the stability region of load.

#### IV. REDUCED ORDER MODEL FOR THE BIFURCATION ANALYSIS

In section III, the parameter stability region analysis of the proposed microgrid is carried out using the full-order model, which is complex and brings huge computation burdens for plotting the bifurcation boundaries. For a microgrid in operation, the plotted stability region can be used to predict the stability margin according to its current state, which is useful for the online scheduling of control parameters. Thus, reducing the computation time is the key to make sure the timely response of DG. In this section, reduced-order models of the MG are developed to improve the computation efficiency for bifurcation analysis.

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The singular perturbation method can reduce the order of dynamic model by eliminating the dynamics from part of state variables. As bifurcation phenomenon is activated by changing a specific parameter, in this section, the reduced models are developed to analyze the stability region in terms of control parameters and loads. The reduced model for a bifurcation phenomenon preserves the state variables that are highly related to this bifurcation.

The procedure of the model order reduction is as shown in Fig. 15. The MG can be divided into several subsystems whose dynamic behavior are described by a set of state variables. The state variables from the bus voltage are not included due to their negligible influence on the system dynamics. Table III presents the classified subsystem and their corresponding state variables. The subsystems are classified into fast and slow subsystems according to the participation analysis results. The dynamics from the slow subsystem will be preserved in the final reduced model.

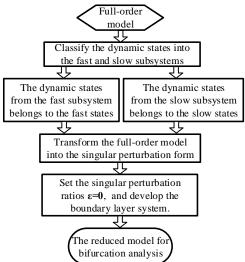


Fig. 15. The procedure of model order reduction.

The major participants of dominant modes are preserved in all reduced models to define the equilibrium of the MG model. HB as a dynamic bifurcation can be detected when a pair of eigenvalues pass through the imaginary axis. Therefore, the state variables related to these eigenvalues need to be preserved in the reduced model for HB calculation. Participation analysis is applied to identify the state variables associated with bifurcation phenomenon. The participation factor is a measure of the relative participation of the *k*th state variable in the *i*th mode, and vice versa. The participation factor of the *i*th mode and *j*th state is given by:

$$p_{ij} = \frac{|u_{ij}^{T}||v_{ij}|}{\sum_{k=1}^{N} |u_{kj}^{T}||v_{jk}|}$$
(27)

where  $u_{ij}$  and  $v_{ij}$  denotes the left eigenvectors and right eigenvectors, respectively. The participation of a subsystem on the mode *i* is defined by summing up all participation factors of

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dynamic states describing this subsystem, which can be written as:

$$p_{i,set\_k} = \sum_{i,j \in set\_k} p_{ij} \tag{28}$$

where the subscript set k denotes the subsystem described by the state variables in *set\_k*.

The effects of the subsystem on the dominant eigenvalues are presented in Table IV. It can be observed that the major participants of dominant eigenvalues are the dynamics from the power controllers and IM loads. The boundary of HB1 shown in Fig. 5 is dominated by a pair of eigenvalues  $\lambda_{2-3}$ . In addition to the dynamics from power controllers, the network dynamic has considerable effect on  $\lambda_{2-3}$ . The boundary of HB2 is dominated by the pair of eigenvalues  $\lambda_{7-8}$ . The dynamics from the inner controller loop, network and power controller have considerable effect on  $\lambda_{7-8}$ . The reduced models for predicting different bifurcation boundaries are organized in Table V. Because the slow states in the two DGs are the same, these states will not be presented in twice.

TABLE III. DYNAMICS OF MG

Subsystem of MG	Dynamics states sets
Power Controller of DGs	$ heta_2$ , P, Q
Inner control loop of DGs	$\varphi_d, \varphi_q, u_{od}, u_{oq}, \gamma_d, \gamma_q, i_{ld}, i_{lq}$
Network dynamics	$i_{od}$ , $i_{oq}$ , $i_{lined}$ , $i_{linq}$
IM load	$\Psi_{rD}, \Psi_{rO}, \omega, i_{sd}, i_{sq}$
ZIP load	$i_{pd}, i_{pa}, i_{ad}, i_{aa}$

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Index	Eigenvalues	Participant dynamics (participation factor)		
$\lambda_I$	-9.8	Rotor side dynamics of IM (0.93)		
$\lambda_{2-3}$	-11.9 ± j53.2 (HB1)	Power controller (0.86), Network dynamics (0.11)		
$\lambda_4$	-29.8	Power controller (0.92)		
$\lambda_5$	-37.3	Power controller (0.85), Rotor side dynamics of IM (0.13)		
$\lambda_6$	$-42.3 \pm j50.1$	Rotor side dynamics of IM (0.83)		
$\lambda_{7-8}$	-56.1 ± j253. 1(HB2)	Inner Control Loop (0.45), Network Dynamics (0.44), Power controller (0.1)		

TABLE V. REDUCED MODEL FOR BIFURCATION ANALYSIS

Bifurcation boundaries	Dynamics preserved in the reduced model	Slow states in the reduced model	Order of the reduced model
SNB with increasing load	Power controller, IM load	$\theta_2$ , P, Q, $\Psi_{rD}$ , $\Psi_{rQ}$ , $\omega$ , $i_{sd}$ , $i_{sq}$ , $u_{bD}$ , $u_{bQ}$	14
HB1 with increasing m <sub>p</sub>	Power controller, IM load Line dynamics	$\theta_2$ , P, Q, $\Psi_{rD}$ , $\Psi_{rQ}$ , $\omega$ , $i_{sd}$ , $i_{sq}$ $i_{od}$ , $i_{oq}$ , $i_{lined}$ , $i_{linq}$ , $u_{bD}$ , $u_{bQ}$	20
HB <sub>2</sub> with increasing m <sub>q</sub>	Power controller, IM load, Line dynamics, Inner control loop	$ \begin{array}{l} \theta_2 \ , \ P, \ Q, \ \Psi_{rD}, \Psi_{rQ}, \ \omega, \ i_{sd}, i_{sq} \\ i_{od}, \ i_{oq}, \ i_{lined}, \ i_{linq}, \ u_{od}, \ u_{oq}, \ i_{ld} \\ i_{lq}, \ \varphi_d, \ \varphi_q, \ \gamma_d, \ \gamma_q, \ u_{bD}, \ u_{bQ} \end{array} $	36

Then, the dynamic model of the MG can be rewritten in a singular perturbation form as:

$$\dot{\boldsymbol{x}} = \boldsymbol{f}(\boldsymbol{x}, \boldsymbol{z}, t, \varepsilon) \tag{29}$$

$$\varepsilon \dot{z} = g(x, z, t, \varepsilon) \tag{30}$$

where  $\varepsilon = \text{diag}\{\varepsilon_1, \varepsilon_2, \dots, \varepsilon_m\}$  denotes a diagonal matrix whose elements are the ratios of physical parameters that reflect the "true smallness" [23]. Subsequently, the state equations of the fast state variables (30) are transformed into the boundary layer system by setting  $\varepsilon$  to be 0, and the quasi-steady-state solution of fast states are presented by *x* as:

$$=h(x,t) \tag{31}$$

Finally, the reduced dynamic model can be obtained by substituting (31) into (29) as:

$$\dot{\boldsymbol{x}} = \boldsymbol{f}(\boldsymbol{x}, \boldsymbol{h}(\boldsymbol{x}, t), t, 0) \tag{32}$$

Thus, the slow dynamics of the original system are preserved in (32), and the original fast states can be described by the algebraic equation (31). The boundary layer system for the SNB is presented in the Appendix.

The bifurcation analysis is performed to compare the calculation times of the reduced-order models with those of the full-order model. The start point is the equilibrium of the MG with the parameters in Table I and Table II. The reduced model for SNB is used to predict the SNB point with load increasing as shown in Fig. 10. The calculation times of bifurcation boundary based on the reduced models are much smaller than those based on the full-order models.

TABLE VI. COMPARISON OF TIME FOR BIFURCATION ANALYSIS

Case	Calculation time for the proposed reduced model	
SNB (Increase of IM loads)	14.6s	37.8s
SNB (Increase of constant power loads)	17.5s	55.4s
HB1 (Increase of active power gain $m_p$ )	2.2s	13.3s

To validate the accuracy of the reduced model, the calculation error of the proposed model is compared with that of the reduced models in [21] and [23], as presented in Table VII. The error of the reduced model is measured as:

$$error = \left| \frac{\lambda_{re} - \lambda_{full}}{\lambda_{full}} \right| \times 100\%$$
(33)

where  $\lambda_{full}$  and  $\lambda_{re}$  denotes the bifurcation parameter of full-order model and reduced model at the bifurcation point, respectively. In [21, 23], the general reduced model for different cases is designed. In [21], the dynamics from the power controller and connection line are preserved in the reduced model. [23] preserves the dynamics from the power controller and inner control loop. The proposed models are more accurate than the general reduced model which indicates that for a specific bifurcation phenomenon, the corresponding reduced model should be designed for an accurate result.

TABLE VII. COMPARISON OF ERRORS FOR BIFURCATION ANALYSIS

Case	Proposed Models	Reduced model in [21]	Reduced model in [23]
SNB (Increase of ZIP loads)	0	0	0
HB1 (Increase of active power gain $m_p$ )	9.6%	9.6%	17.1%
HB2 (Increase of active power gain $m_q$ )	2.3%	29.8%	12.1%

#### V. VERIFICATION

### A. Simulation Results

In this section, the bifurcation phenomena and the parameter stability region analysis are validated using the switching testbed of the proposed MG built in the MATLAB/SymPowerSystem environment. The parameters from Tables I and II are used. To validate the parameter stability region composed of HB boundaries, the simulation results when active power gains  $m_{p1}$  and  $m_{p2}$  switch from  $m_{p1} = 1.5e^{-4}$  and  $m_{p2} = 3e^{-4}$  to  $m_{p1} = 7.5e^{-4}$  and  $m_{p2} = 15e^{-4}$  coordinately at 3 s are shown in Fig. 16. The waveform starts to oscillate at 3 s, after which the magnitude of the oscillation gradually become larger. This kind of nonlinear phenomenon belongs to the subcritical HB, and coincides with the analysis in Section III.

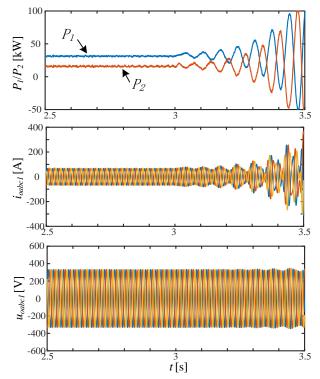


Fig. 16. Simulation results of DG1 when the active gains are switched from  $m_{p1} = 1.5e^{-4}$  and  $m_{p2} = 3e^{-4}$  to  $m_{p1} = 7.5e^{-4}$  and  $m_{p2} = 15e^{-4}$  at 3 s

The parameter stability region of the ZIP load shown in Fig. 10 is validated by the simulation results, as shown in Fig. 17. The active power in the ZIP load continuously increases by connecting the input reference value port of the load module in MATLAB/SymPowerSystem to a ramp signal source. When the ZIP load is composed of a 100% constant-power load component, the voltage decreases and collapses at 3.2 s. Fig. 19 shows the voltage at bus 2 with a 37.5-kW IM load in large time scale. The parameters of this IM load are designed according to Table II. At 2 s, a 15-kW IM load with an IM load factor K = 15/22.5 is connected to bus 2. The bus voltage decreases continuously after the step change of IM load, and the angular velocity will eventually decrease to 0 rads/s.

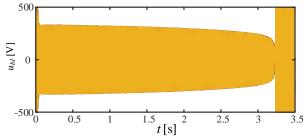
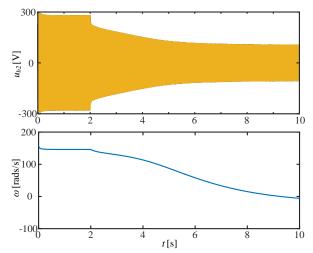


Fig. 17. The phase voltage at bus 2 with the increase of the rated active power at a ZIP load that consists of 100% constant active power load. The SNB appears and then system collapses.



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Fig. 18. The phase voltage at bus 2 with the increase of the IM load. The system collapses and SNB appears after the connection of the 15 kW IM load.

Fig. 19 is plotted to validate the influence of virtual inductance control and droop control on the SNB boundaries. The constant power load with 50kW nominal active power is connected to bus 2. In Fig. 19(a) the virtual inductance is switched from 4mH to 6mH at 2s, the voltage collapse after 2s. In Fig. 19(b), the nominal voltage in power controller is switched from 330V to 300V at 2s, the bus voltage continuously decrease, and eventually collapse after 3.3s.

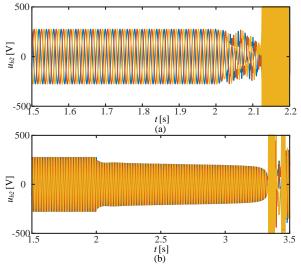


Fig. 19. The phase voltage at bus 2 with 50kW ZIP load. (a) The virtual inductance of is switched from 4mH to 6mH at 2s. (b) The nominal voltage of droop controller is switched from 330V to 300V at 2s.

#### B. Experimental Results

The hardware in-the-loop (HIL) method is proposed for the experiment verification in this section. All the electrical components including power electronic inverters, network, ZIP load and IM load are simulated at real time in RT-LAB [30]. The two droop-controlled inverters are controlled via two real DSP controllers, respectively. The parameters of droop controllers and electrical circuit are the same as shown in Table I and Table II.

Fig. 20 shows the waveforms of the DG1 after the subcritical HB. The active power gains of two DG  $m_{p1}$  and  $m_{p2}$  are switched from  $m_{p1} = 1.5e^{-4}$ ,  $m_{p2} = 3e^{-4}$  to  $m_{p1} = 7.5e^{-4}$ ,  $m_{p2} = 15e^{-4}$  coordinately. Since the output ranges of the analog out ports are

limited, the maximum permissible magnitude of output current signals is 100 A. The output voltages and currents of the DGs fluctuate after the subcritical bifurcation, which coincides with the bifurcation analysis and the simulation results.

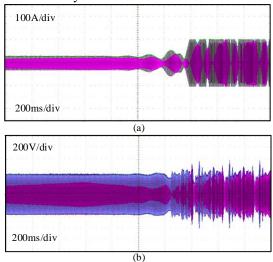


Fig. 20. Experiment results of the subcritical HB. (a) Output currents. (b). Output voltages.

Fig. 21 shows the experiment result of the SNB as load increases. The voltage of Bus 2 decreases with the continuous increment of the constant power load, and eventually, the voltage collapses. This result is in accordance with the simulated result given in Fig. 18 and Fig. 19. The SNB phenomenon caused by the increment of the IM load is verified. A 37.5 kW IM load is connected to the Bus 2 at first. Then, a 15 kW IM load is integrated. The voltage of Bus 2 droops irreversibly, which coincides with the simulation result as shown in Fig. 19.

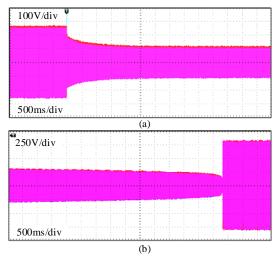


Fig. 21. Experiment results of the SNBs. (a) The IM load steps from 37.5 kW to 52.5kW. (b) Constant active-power load increases.

# VI. CONCLUSION

This paper studies the modeling and parameter stability region analysis of a droop-controlled MG with dynamic IM load and static ZIP load. Reduced-order models for parameter stability region analysis are presented based on the singular perturbation method. Several conclusions are obtained. 1) The equivalent model of ZIP load and IM load are developed to combine a complete model of MG, which can describe the load increasing for bifurcation analyses.

2) The SNB and HB boundaries constitute the parameter stability region of MG with ZIP and IM load. The HB of power droop gain are related to dynamics from the power controller and network of DGs. The SNB of load are related to the coupling inductance, connection line and voltage control.

3) The reduced-order models for numerical bifurcation analysis predicts the bifurcation phenomena with low computation burden. The dynamics of power controllers and IM loads have major influence on the SNB with load increasing and should be preserved in the reduced model for predicting SNB. The reduced model for predicting the HB with the change of active-power droop gain should preserve the dynamics of power controllers, IM loads and network dynamics. The reduced model for predicting the HB with the change of reactive-power droop gain can only eliminate the dynamics of ZIP loads.

#### APPENDIX

The boundary layer system of the reduced model is presented in this section. According to the description on section IV, the differential equations of fast states are degraded to the algebraic equations. The algebraic part of the reduced model for predicting the SNB that eliminates most dynamics of subsystems is presented in detail. After classifying the dynamic states into the slow-state vector x and fast-state vector z, the state equations of inner control loop, line dynamics and ZIP load are normalized as the singular perturbation form zoo

as: { 
$$\frac{1}{K_{vi}}\varphi_d$$
,  $\frac{1}{K_{vi}}\varphi_q$ ,  $C_f u_{odi}$ ,  $C_f u_{oqi}$ ,  $\frac{1}{K_{ci}}\gamma_d$ ,  $\frac{1}{K_{ci}}\gamma_q$ ,  $\frac{L_f}{R_f}i_{ldi}$ ,  
 $\frac{L_f}{K_{vi}}i_{vi}$ ,  $\tau i_{ci}$ ,  $\tau i_{ci}$ ,  $\tau i_{ci}$ ,  $\tau i_{ci}$ ,  $\frac{L_g}{K_f}i_{vi}$ ,  $\frac{L_g}{K_f}i_{vi}$ ,  $\frac{L_{line}}{K_f}i_{vi}$ ,  $\tau i_{ci}$ ,  $\tau i_{c$ 

 $\frac{\overline{R_f}}{R_f} l_{lqi} , \tau l_{GD} , \tau l_{GQ} , \tau l_{BD} , \tau l_{BQ} , \overline{R_g} l_{od} , \overline{R_g} l_{oq} , \overline{R_g} l_{ine} i_{lined} ,$   $I_{co}$ 

 $\frac{L_{line}}{R_{line}}$  i<sub>lineq</sub> }. By setting  $\varepsilon = 0$ , the dynamic equations of the fast

states degenerate into the boundary layer system. Then, Gaussian elimination is applied to obtain the quasi-steady-state solution of fast states.

The inner control loop can be presented in algebraic form as:

$$u_{od} = U_n - n_q Q, \ u_{oq} = 0,$$
 (A1)

$$i_{ld} = i_{od}, i_{lq} = i_{oq} + \omega C_f (U_n - n_q Q).$$
 (A2)

The output current can be written in algebraic form by

$$i_{oD} = \frac{R_g (u_{oD} - u_{bD}) + \omega_{com} L_g (u_{oQ} - u_{bQ})}{R_g^2 + \omega_{com}^2 L_g^2}, \qquad (A3)$$

$$i_{oQ} = \frac{R_g (u_{oQ} - u_{bQ}) - \omega_{com} L_g (u_{oD} - u_{bD})}{R_g^2 + \omega_{com}^2 L_g^2} \,.$$
(A4)

The line current between bus1 and bus2 can be written as:

$$\dot{i}_{lineD} = \frac{R_{line}(u_{b1D} - u_{b2D}) + \omega_{com}L_{line}(u_{b1Q} - u_{b2Q})}{R_{line}^2 + \omega_{com}^2 L_{line}^2}, \quad (A5)$$

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$$i_{lineQ} = \frac{R_{line}(u_{b1Q} - u_{b2Q}) - \omega_{com}L_{line}(u_{b1D} - u_{b2D})}{R_{line}^2 + \omega_{com}^2 L_{line}^2} \,.$$
(A6)

The ZIP load is presented in algebraic form as:

$$i_{PD} = G_{ZIP} u_{bD}, \quad i_{PQ} = G_{ZIP} u_{bQ}, \quad (A7)$$

$$i_{QD} = -B_{ZIP}u_{bQ} , \ i_{QQ} = B_{ZIP}u_{bQ} .$$
 (A8)

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